

Cover Page



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# **Conductance and Gating Effects at Sputtered Oxide Interfaces**

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About the cover: The cover shows an illustration of the  $\text{LaAlO}_3/\text{SrTiO}_3$  interface. The left side is the  $\text{LaAlO}_3$  film and the right side is the  $\text{SrTiO}_3$  substrate. The light blue, dark blue, orange, red and gray spheres represent La, Al, Sr, Ti and O atoms, respectively. The light gray squares represent oxygen octahedra.

*To my grandfather*



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